



# 1.5MHz, 600mA Synchronous Step-Down Regulator

#### Features

- High Efficiency: Up to 96%
- Very Low Quiescent Current: 300µA
- 600mA Output Current
- 2.5V to 6.5V Input Voltage Range
- 1.5MHz Constant Frequency Operation
- · No Schottky Diode Required
- Low Dropout Operation: 100% Duty Cycle
- 0.6V Reference Allows Low Output Voltages
- Shutdown Mode Draws ≤ 1µA Supply Current
- Current Mode Operation for Excellent Line and Load Transient Response
- Over temperature Protected

#### General Description

The RCR2001 series are a high efficiency monolithic synchronous buck regulator using a constant frequency, current mode architecture. The device is available in an adjustable version and fixed output voltages of 1.2V, 1.5V and 1.8V. Supply current during operation is only  $300\mu\text{A}$  and drops to  $\leq 1\mu\text{A}$  in shutdown. The 2.5V to 6.5V input voltage range

makes the RCR2001 ideally suited for single Li-lon battery-powered applications. 100% duty cycle provides low dropout operation, extending battery life in portable systems. Automatic Burst Mode operation increases efficiency at light loads, further extending battery life.

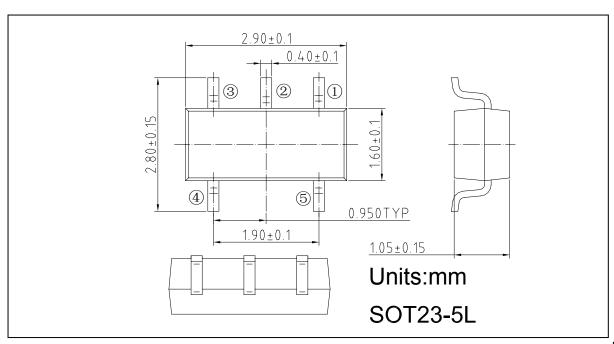
Switching frequency is internally set at 1.5MHz, allowing the use of small surface mount inductors and capacitors.

The internal synchronous switch increases efficiency and eliminates the need for an external Schottky diode. Low output voltages are easily supported with the 0.6V feedback reference voltage. The RCR2001 is available in a low profile (1mm) Thin SOT23-5L package.

#### Applications

- · Cellular Telephones
- · Personal Information Appliances
- Wireless and DSL Modems
- Digital Still Cameras
- MP3 Players
- Portable Instruments

# Package Information

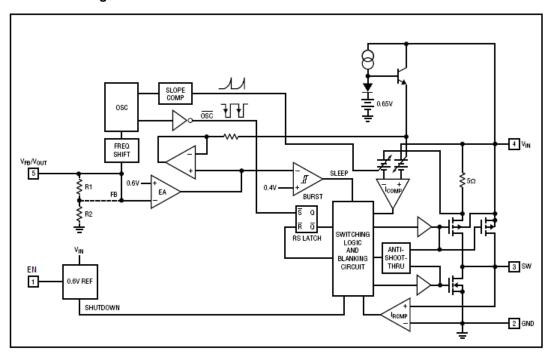




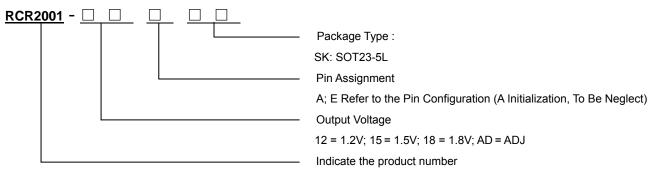
# Pin Configurations

	Pin Configurations Code										
Pin Type	A(Initialization)			E							
Pin Name	SOT23-5L			Pin Name	SOT23-5L						
Pin Name	RCR2001-AD	RCR2001-FIXED		Pin Name	RCR2001-AD	RCR2001-FIXED					
1)	EN	EN		1)	VIN	VIN					
2	GND	GND		2	GND	GND					
3	SW	SW		3	EN	EN					
4	VIN	VIN		4	VFB	VOUT					
(5)	VFB	VOUT		5	SW	SW					

# • Functional Block Diagram



# Ordering Information





# Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Supply Voltage	V <sub>IN</sub>	-0.3 to 7	V
EN,VFB Voltages	V <sub>EN</sub>	-0.3 to V <sub>IN</sub>	V
SW Voltage	V <sub>SW</sub>	-0.3 to V <sub>IN</sub> +0.3	V
P-Channel Switch Source Current ( DC )		800	mA
N-Channel Switch Sink Current (DC)		800	mA
Peak SW Sink and Source Current	I <sub>PK</sub>	1.3	Α
Operation Temperature	T <sub>OPR</sub>	-40 to +85	$^{\circ}$
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	$^{\circ}$

### • Electrical Characteristics

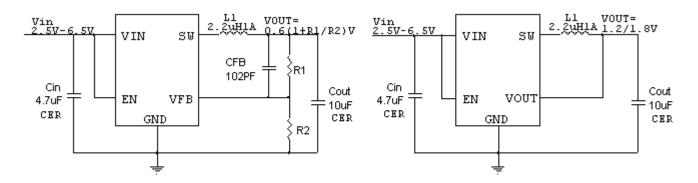
TA = 25°C. V<sub>IN</sub> = 3.6V unless otherwise specified.

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Feedback Current	I <sub>FB</sub>				±30	nA
Regulated Feedback Voltage	$V_{FB}$	T <sub>A</sub> = 25°C 0°C ≤ TA ≤ 85°C -40°C ≤ T <sub>A</sub> ≤ 85°C	0.588 0.586 0.585	0.6 0.6 0.6	0.612 0.613 0.615	V V
Reference Voltage Line Regulation	$\Delta V_{FB}$	V <sub>IN</sub> = 2.5V to 5.5V		0.04	0.4	%/V
Regulated Output Voltage	V <sub>OUT</sub>	RCR2001 - 1.2, I <sub>OUT</sub> = 100mA RCR2001 - 1.5, I <sub>OUT</sub> = 100mA RCR2001 - 1.8, I <sub>OUT</sub> = 100mA	1.164 1.455 1.746	1.2 1.500 1.800	1.236 1.545 1.854	V
Output Voltage Line Regulation	$\Delta V_{OUT}$	V <sub>IN</sub> = 2.5V to 5.5V		0.04	0.4	%/V
Peak Inductor Current	I <sub>PK</sub>	$V_{IN} = 3V$ , $V_{FB} = 0.5V$ or $V_{OUT} = 90\%$ , Duty Cycle < 35%	0.75	1	1.25	Α
Output Voltage Load Regulation	V <sub>LOADREG</sub>			0.5		%
Input Voltage Range	V <sub>IN</sub>		2.5		6.5	V
Input DC Bias Current Active Mode Sleep Mode Shutdown	Is	$V_{FB}$ = 0.5V or $V_{OUT}$ = 90%, $I_{LOAD}$ = 0A $V_{FB}$ = 0.62V or $V_{OUT}$ = 103%, $I_{LOAD}$ = 0A $V_{EN}$ = 0V, $V_{IN}$ = 4.2V		300 20 0.1	400 35 1	μΑ μΑ μΑ
Oscillator Frequency	Fosc	V <sub>FB</sub> = 0.6V or V <sub>OUT</sub> = 100%	1.2	1.5	1.8	MHz
RDS ( ON ) of P-Channel FET	R <sub>PFET</sub>	I <sub>SW</sub> = 300mA		0.4	0.5	Ω
RDS ( ON ) of N-Channel FET	R <sub>NFET</sub>	I <sub>SW</sub> = -300mA		0.35	0.45	Ω
SW Leakage	I <sub>LSW</sub>	$V_{EN} = 0V$ , $V_{SW} = 0V$ or 5V, $V_{IN} = 5V$		±0.01	±1	μA
EN Input Logic Low Threshold	V <sub>IL</sub> *	T <sub>J</sub> = -40°C to 125°C		-	0.3	V
EN Input Logic High Threshold	V <sub>IH</sub>	T <sub>J</sub> = -40°C to 125°C	1.5			V
EN Leakage Current	I <sub>EN</sub>			±0.01	±1	μA

<sup>\*</sup> If need to use the EN pin to close output, please make sure the EN level lower than 0.3V, otherwise may not be able to turn-off.



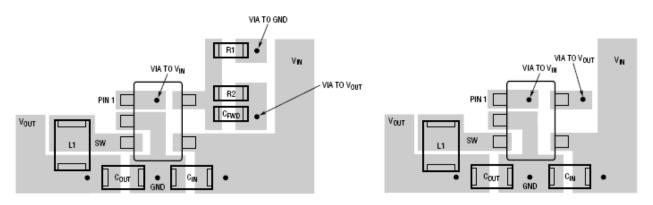
#### Typical Application Circuit



#### **PCB Layout Checklist**

When laying out the printed circuit board, the following checklist should be used to ensure proper operation of the RCR2001. Check the following in your layout:

- 1. The power traces, consisting of the GND trace, the SW trace and the V<sub>IN</sub> trace should be kept short, direct and wide.
- 2. Does the V<sub>FB</sub> pin connect directly to the feedback resistors? The resistive divider R1/R2 must be connected between the ( + ) plate of C<sub>OUT</sub> and ground.
- 3. Does the ( + ) plate of  $C_{IN}$  connect to  $V_{IN}$  as closely as possible? This capacitor provides the AC current to the internal power MOSFETs.
- 4. Keep the switching node, SW, away from the sensitive  $V_{FB}$  node.
- 5. Keep the ( ) plates of  $C_{\text{IN}}$  and  $C_{\text{OUT}}$  as close as possible.



RCR2001-ADJ Suggested Layout

RCR2001-1.8V Suggested Layout



### Typical Performance Characteristics

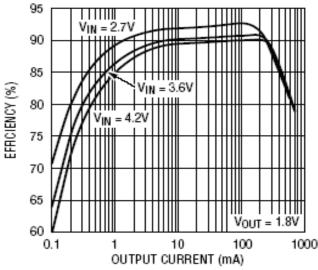


Figure 1. Efficiency vs. Output Current

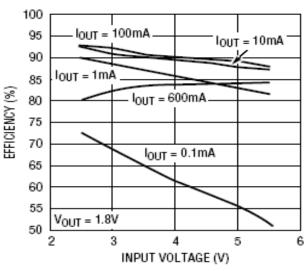


Figure 2. Efficiency vs. Input Voltage

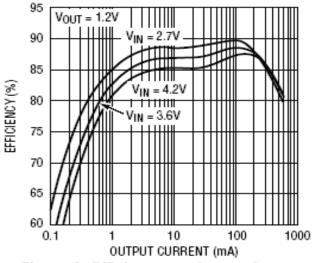


Figure 3. Efficiency vs. Output Current

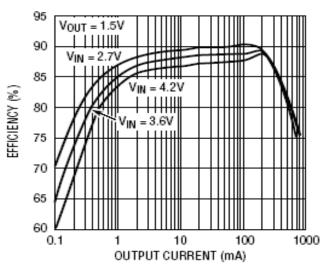


Figure 4. Efficiency vs. Output Current



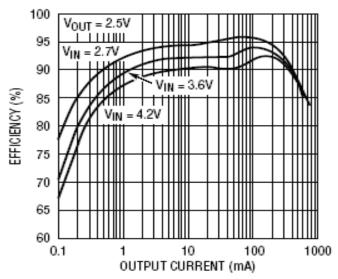


Figure 5. Efficiency vs. Output Current

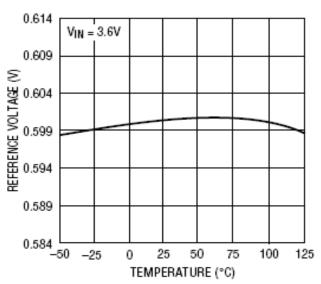


Figure 6. REF Voltage vs. Temperature

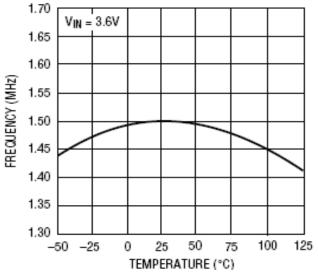


Figure 7. Frequency vs. Temperature

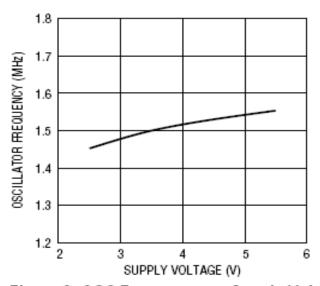


Figure 8. OSC Frequency vs. Supply Voltage



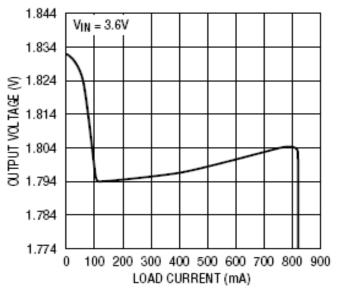


Figure 9. Output Voltage vs. Load Current

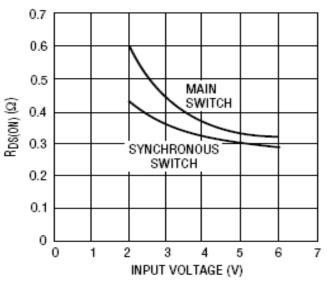


Figure 10. Rds(on) vs. Input Voltage

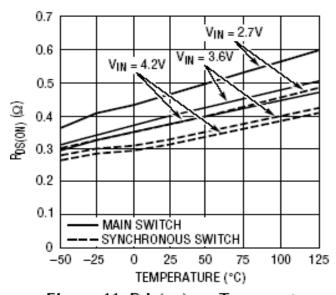


Figure 11. Rds(on) vs. Temperature

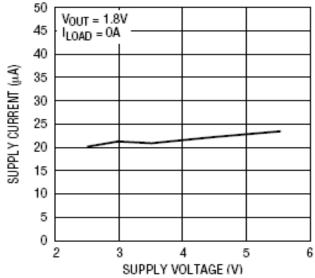


Figure 12. Supply Current vs. Supply Voltage

125



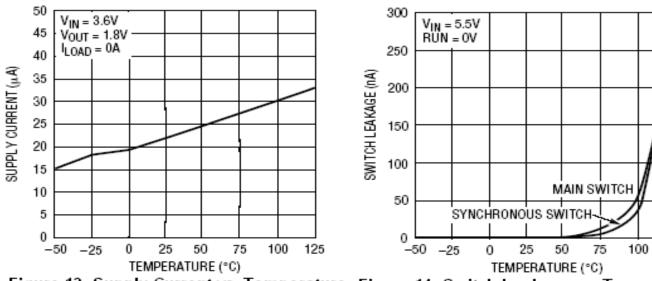


Figure 13. Supply Current vs. Temperature Figure 14. Switch Leakage vs. Temperature

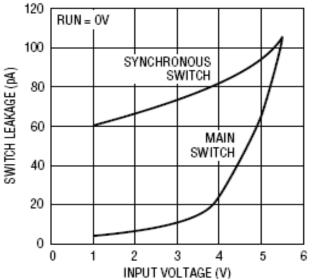


Figure 15. Switch Leakage vs. Input Voltage

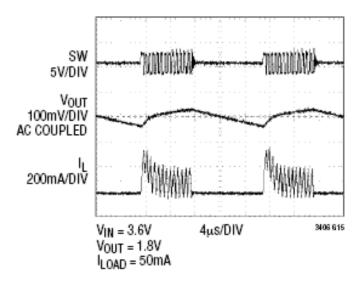


Figure 16. Boost Mode Operation





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